

3.3V CMOS 16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS AND 5 VOLT TOLERANT I/O

IDT74LVC162245A

FEATURES:

- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4µ W typ. static)
- · All inputs, outputs, and I/O are 5V tolerant
- · Available in SSOP and TSSOP packages

DRIVE FEATURES:

- Balanced Output Drivers: ±12mA (A port)
- High Output Drivers: ±24mA (B port)

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- · Data communication and telecommunication systems

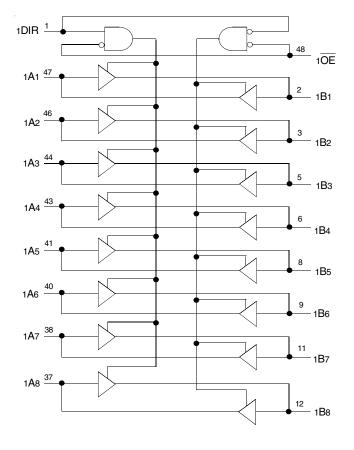
FUNCTIONAL BLOCK DIAGRAM

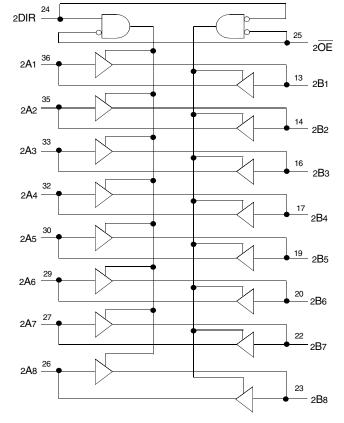
DESCRIPTION:

This 16-bit transceiver is built using advanced dual metal CMOS technology. The LVC162245A is designed for asynchronous communication between data buses. The control-function implementation minimizes external timing requirements. This device can be used as two 8-bit transceivers or one 16-bit transceiver. It allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated. To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

All pins can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V supply system.

The LVC162245A has series resistors in the device output structure of the "A" port which will significantly reduce line noise when used with light loads. The driver has been designed to drive ± 12 mA at the designated threshold levels. The "B" port has a ± 24 mA driver.



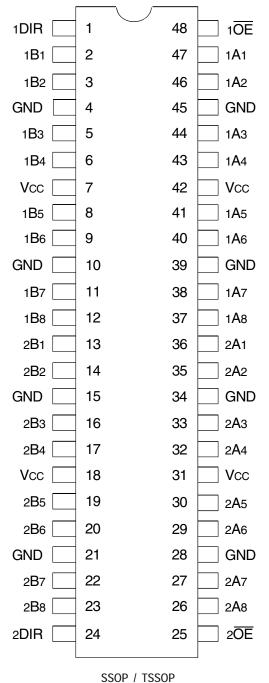


IDT and the IDT logo are registered trademarks of Integrated Device Technology, Inc.

AUGUST 2015

IDT74LVC162245A 3.3V CMOS16-BIT TRANSCEIVER WITH 3-STATE OUTPUTS

PIN CONFIGURATION



TOP VIEW

INDUSTRIAL TEMPERATURE RANGE

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	–0.5 to +6.5	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	–0.5 to +6.5	V
Tstg	Storage Temperature	–65 to +150	°C
Ιουτ	DC Output Current	–50 to +50	mA
Ік Іок	Continuous Clamp Current, Vi < 0 or Vo < 0	-50	mA
lcc Iss	Continuous Current through each Vcc or GND	±100	mA

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	6.5	8	pF
CI/O	I/O Port Capacitance	VIN = 0V	6.5	8	pF

NOTE:

1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	ames Description	
x OE Output Enable Input (Active LOW)		
xDIR Direction Control Output		
xAx Side A Inputs or 3-State Outputs		
xBx	Side B Inputs or 3-State Outputs	

FUNCTION TABLE (EACH 8-BIT SECTION)(1)

Inputs		
xOE	xDIR	Outputs
L	L	B Data to A Bus
L	Н	A Data to B Bus
Н	Х	Isolation

NOTE:

1. H = HIGH Voltage Level

X = Don't Care

L = LOW Voltage Level

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Operating Condition: TA = -40 °C to +85 °C

Symbol	Parameter	Test	Conditions	Min.	Тур. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	-	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	V
		Vcc = 2.7V to 3.6V		_	—	0.8	
liн liL	Input Leakage Current	Vcc = 3.6V	VI = 0 to 5.5V	-	-	±5	μA
Iozh Iozl	High Impedance Output Current (3-State Output pins)	Vcc = 3.6V	Vo = 0 to 5.5V	-	_	±10	μA
loff	Input/Output Power Off Leakage	Vcc = 0V, VIN or Vo ≤ 5.5 V	1	_	-	±50	μA
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA		-	-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
ICCL ICCH	Quiescent Power Supply Current	Vcc = 3.6V	VIN = GND or VCC	-	—	10	μA
lccz			$3.6 \le VIN \le 5.5V^{(2)}$	—	—	10	
∆lcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, oth	er inputs at Vcc or GND	_	_	500	μA

NOTES:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

2. This applies in the disabled state only.

OUTPUT DRIVE CHARACTERISTICS (A PORT)

Symbol	Parameter	TestC	onditions ⁽¹⁾	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Iон = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	Iон = - 4mA	1.9	_	
			Iон = - 6mA	1.7	_	
		Vcc = 2.7V	Iон = - 4mA	2.2	_	
			Iон = - 8mA	2	_	
		Vcc = 3V	Iон = - 6mA	2.4	_	
			Іон = – 12mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	—	0.2	V
		Vcc = 2.3V	IoL = 4mA	_	0.4	
			IoL = 6mA		0.55	
		Vcc = 2.7V	IoL = 4mA		0.4	
			IoL = 8mA	_	0.6	
		Vcc = 3V	IoL = 6mA	—	0.55	
			IoL = 12mA	_	0.8	

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = − 40°C to + 85°C.

INDUSTRIAL TEMPERATURE RANGE

OUTPUT DRIVE CHARACTERISTICS (B PORT)

Symbol	Parameter	TestCon	ditions ⁽¹⁾	Min.	Max.	Unit
Voн	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Іон = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	Iон = - 6mA	2	_	
		Vcc = 2.3V	Іон = – 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3V]	2.4	—	
		Vcc = 3V	Іон = — 24mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	—	0.2	V
		Vcc = 2.3V	IoL = 6mA	—	0.4	
			IoL = 12mA	—	0.7	
		Vcc = 2.7V	IoL = 12mA	—	0.4	
		Vcc = 3V	IoL = 24mA	_	0.55	

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = − 40°C to + 85°C.

OPERATING CHARACTERISTICS, Vcc = 3.3V ± 0.3V, TA = 25°C

Symbol	Parameter	Test Conditions	Typical	Unit
Cpd	Power Dissipation Capacitance per Transceiver Outputs enabled	CL = 0pF, f = 10Mhz		pF
Cpd	Power Dissipation Capacitance per Transceiver Outputs disabled			

SWITCHING CHARACTERISTICS (A PORT)⁽¹⁾

		Vcc =	= 2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tPLH	Propagation Delay	1.5	5.7	1.5	4.8	ns
t PHL	xBx to xAx					
tРZH	Output Enable Time	1.5	7.9	1.5	6.3	ns
tPZL	xOE to xAx					
tPHZ	Output Disable Time	1.5	8.3	2.2	7.4	ns
tPLZ	xOE to xAx					
tsk(o)	Output Skew ⁽²⁾	_	—	_	500	ps

NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. TA = -40° C to + 85°C.

2. Skew between any two outputs of the same package and switching in the same direction.

SWITCHING CHARACTERISTICS (B PORT)⁽¹⁾

		Vcc =	= 2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tPLH	Propagation Delay	1.5	4.7	1	4	ns
t PHL	xAx to xBx					
tРZH	Output Enable Time	1.5	6.7	1.5	5.5	ns
tPZL	xOE to xBx					
tPHZ	Output Disable Time	1.5	7.1	1.5	6.6	ns
tPLZ	xOE to xBx					
tsk(o)	Output Skew ⁽²⁾	_	—		500	ps

NOTES:

^{1.} See TEST CIRCUITS AND WAVEFORMS. TA = - 40°C to + 85°C.

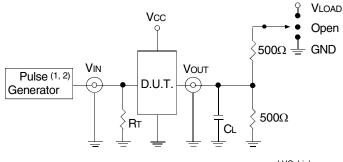
^{2.} Skew between any two outputs of the same package and switching in the same direction.

IDT74LVC162245A 3.3V CMOS 16-BIT TRANSCEIVER WITH 3-STATE OUTPUTS

INDUSTRIAL TEMPERATURE RANGE

TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS

Symbol	Vcc ⁽¹⁾ =3.3V±0.3V	Vcc ⁽¹⁾ =2.7V	$Vcc^{(2)} = 2.5V \pm 0.2V$	Unit
VLOAD	6	6	2 x Vcc	V
Vih	2.7	2.7	Vcc	V
Vт	1.5	1.5	Vcc/2	V
Vlz	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	рF



LVC Link

Test Circuit for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

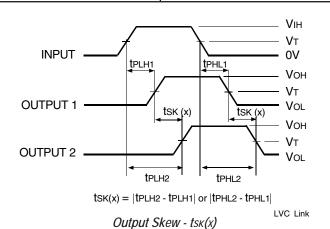
 $\mathsf{R} \tau$ = Termination resistance: should be equal to $\mathsf{Z} \mathsf{O} \mathsf{U} \tau$ of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns. 2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

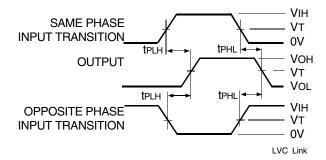
Test	Switch
Open Drain Disable Low Enable Low	Vload
Disable High Enable High	GND
All Other Tests	Open



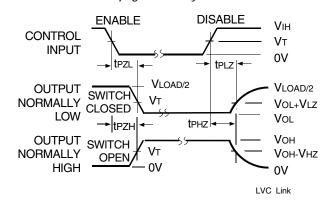
NOTES:

1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.

2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



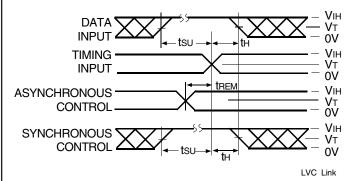
Propagation Delay

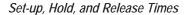


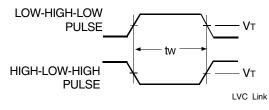
Enable and Disable Times

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.







Pulse Width

ORDERING INFORMATION

